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## APPLICANTS

Seok-Woo Lee, Gyeonggi-do, KOREA, REPUBLIC OF;

\*\* CONTINUING DATA \*\*\*\*\* none

\*\* FOREIGN APPLICATIONS \*\*\*\*\* SDF  
 REPUBLIC OF KOREA 2002-53086 09/04/2002

IF REQUIRED, FOREIGN FILING LICENSE GRANTED

\*\* 11/19/2003

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance met Verified and Acknowledged Examiner's Signature <i>Stanley Lee</i> Initials <i>SDF</i>	STATE OR  COUNTRY KOREA, REPUBLIC OF	SHEETS  DRAWING 9	TOTAL  CLAIMS 25	INDEPENDENT  CLAIMS 2
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## TITLE

Method of fabricating top gate type thin film transistor having low temperature polysilicon

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